

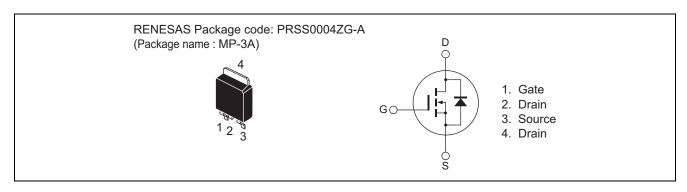
# RJK6032DPD

600V - 3A - MOS FET High Speed Power Switching R07DS0837EJ0300 Rev.3.00 Oct 05, 2012

### **Features**

- Low on-resistance  $R_{DS(on)}=3.3~\Omega~typ.~(at~I_D=1.5~A,~V_{GS}=10~V,~Ta=25^{\circ}C)$
- Low drive current
- High density mounting

### **Outline**



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	600	V
Gate to source voltage	V <sub>GSS</sub>	±30	V
Drain current	I <sub>D</sub>	3	А
Drain peak current	I <sub>D (pulse)</sub> Note1	6	А
Body-drain diode reverse drain current	I <sub>DR</sub>	3	А
Body-drain diode reverse drain peak current	I <sub>DR</sub> (pulse)	6	А
Avalanche current	I <sub>AP</sub> Note2	3	А
Avalanche energy	E <sub>AR</sub> Note2	0.49	mJ
Channel dissipation	Pch Note3	40.3	W
Channel to case thermal impedance	θch-c	3.1	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. Pulse width limited by operating area.

- 2. STch =  $25^{\circ}$ C, Tch  $\leq 150^{\circ}$ C
- 3. Value at Tc = 25°C

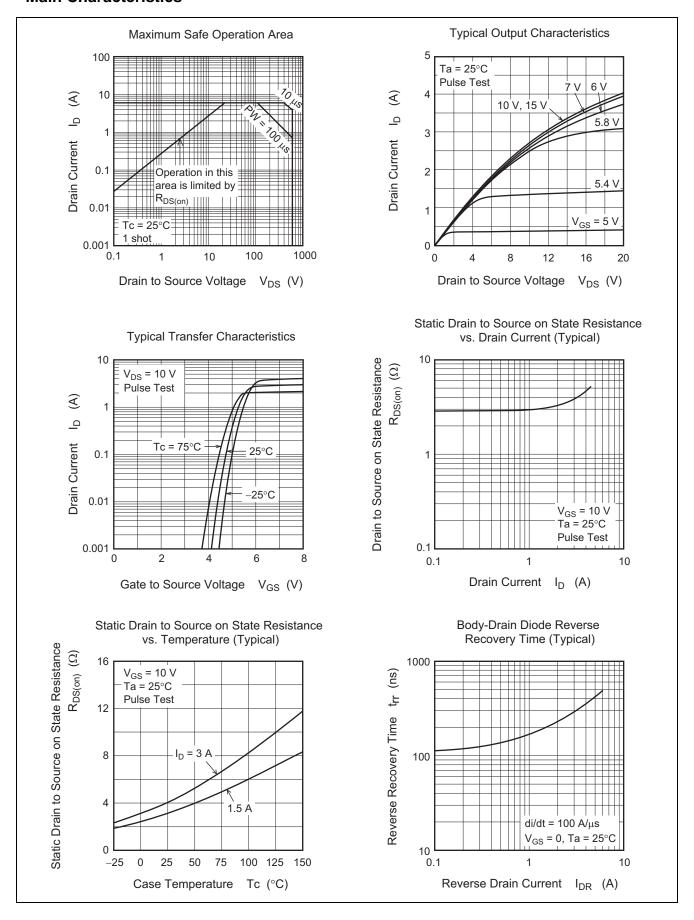
## **Electrical Characteristics**

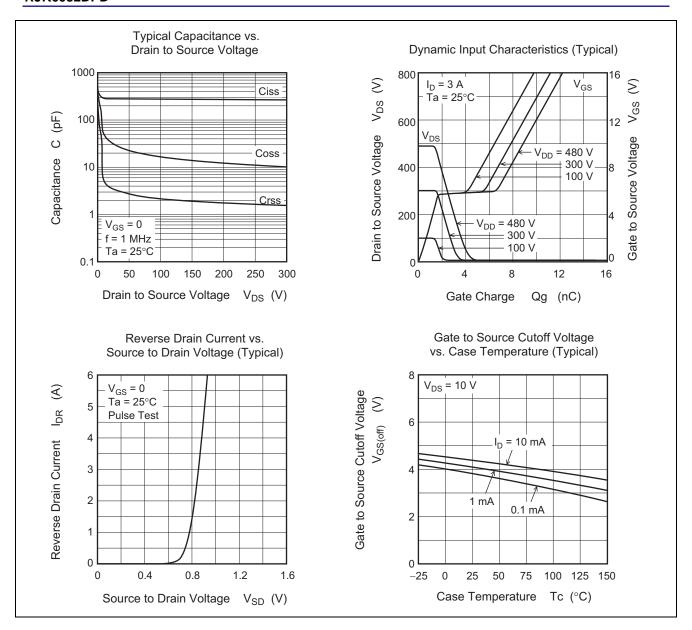
 $(Ta = 25^{\circ}C)$ 

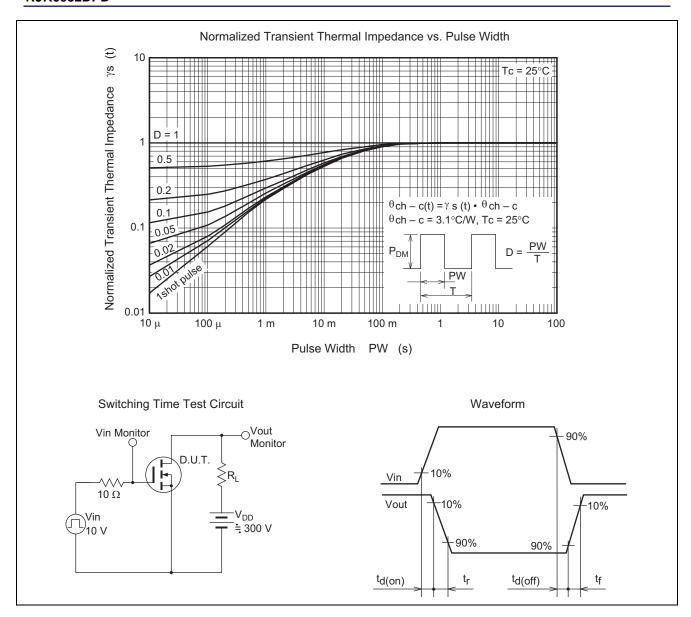
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	600			V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>			1	μΑ	$V_{DS} = 600 \text{ V}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±0.1	μА	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	3.5	_	4.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state resistance	R <sub>DS(on)</sub>	_	3.3	4.3	Ω	$I_D = 1.5 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
Input capacitance	Ciss	_	285	_	pF	V <sub>DS</sub> = 25 V
Output capacitance	Coss	_	31	_	pF	V <sub>GS</sub> = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	3.5	_	pF	
Turn-on delay time	t <sub>d(on)</sub>	_	13	_	ns	$I_D = 1.5 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 200 \Omega$ $Rg = 10 \Omega$
Rise time	t <sub>r</sub>	_	13	_	ns	
Turn-off delay time	t <sub>d(off)</sub>	_	22	_	ns	
Fall time	t <sub>f</sub>	_	22	_	ns	
Total gate charge	Qg	_	9.0	_	nC	$V_{DD} = 480 \text{ V}$ $V_{GS} = 10 \text{ V}$ $I_{D} = 3 \text{ A}$
Gate to source charge	Qgs	_	1.7	_	nC	
Gate to drain charge	Qgd	_	4.9	_	nC	
Body-drain diode forward voltage	$V_{DF}$	_	0.9	1.5	V	$I_F = 3 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	300	_	ns	$I_F = 3 \text{ A}, V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Notes: 4. Pulse test

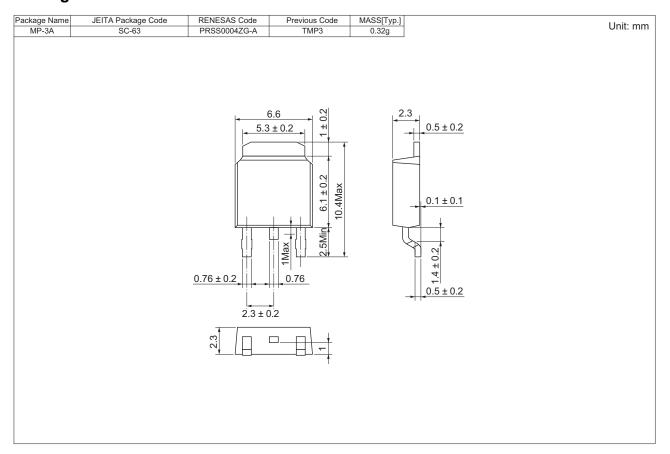
### **Main Characteristics**







## **Package Dimensions**



# **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJK6032DPD-00#J2	3000 pcs	Taping

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